Influence of Fe$_2$O$_3$ Dopant on Dielectric, Optical Conductivity and Nonlinear Optical Properties of Doped ZnO-Polystyrene Composites Films

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Abstract: ZnO-Polystyrene nanoparticles doped with Fe$_2$O$_3$ were prepared by the casting method. Both $E_{g}$ and $E_{v}$ were calculated. $\epsilon_1$ and N/m$^2$ increase with filler concentrations for these samples. On the other hand, both $M_1$, $M_3$, decreased with increasing filler. The filler concentrations affected on determined values of both of $\epsilon^a$ and $\epsilon^b$. These values increase with filler, and also the same result was achieved for both $\sigma_1$ and $\sigma_2$, which also increases with filler. The relation between VELF and SELF was determined. $\chi^{(3)}$ increases with increasing filler ratio. $n_2$, $\chi^{(3)}$, $\beta_c$, were determined theoretically. The electrical susceptibility $\chi$ and relative permittivity $\varepsilon_r$ increase with the increase of filler concentration as a result of increasing electron mobility.

Keywords: Fe$_2$O$_3$ doped with ZnO-polystyrene nanoparticles; dielectric properties; optical conductivity; nonlinear optical properties.

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1. Introduction

have a great interest due to their properties and wide electronic applications [1–4]. Polymer composites are widely used as electrically conductive glues. Polystyrene has high transparency and is used for industrial applications [5, 6] such as chromatography [7], sorption processes [8], sensors [9, 10], biomedical applications [11–12], and other electronic applications [13–14]. Polymers’ matrix properties can be improved by the dispersion of metals in the polymer matrix [15, 16]. Zinc Oxide is a magic material as a result of its properties [17–19]. It has a direct bandgap ($E_g = 3.25$ eV) [20], which is a promising material for optoelectronic applications [21, 22]. On the other hand, ZnO material had some disadvantages, such as a low quantum efficiency [23], so reinforcing particles must be added to ZnO matrix composite, such as Fe$_2$O$_3$ because of its thermodynamic stability, high resistance to photo-corrosion, and narrow bandgap of 2.2 eV. So, Fe$_2$O$_3$ is an important member of visible-light-responsive semiconductor photocatalysts [24–27]. Different methods have been used to synthesize various metal-polymer composites, such as the sol-gel process [28], mixing route of polymer with metal solution [29], chemical oxidation [30], and in-situ techniques [31]. The optical properties of ZnO-Polystyrene...
had been studied [32–36]. It was found that the transmitted spectra are increased with ZnO ratio [32], ZnO percentage had increased absorption ratio for polystyrene [34], ZnO-PS nanocomposite is highly transparent throughout the visible region [35], the energy gap decreased with ZnO ratios for ZnO/PS composite [36]. The doping effect on the optical properties of ZnO/Polystyrene films had been studied [37]. The direct energy gap decreased with increasing Fe₂O₃ for ZnO Polystyrene. The nonlinear optical properties of ZnO-Polystyrene composites had been investigated [38–39]. It was noticed that PS had good applications for nonlinear optical devices [39]. In this work, we investigated the effect of Fe₂O₃ dopant on nonlinear optical properties such as (nonlinear refractive index, nonlinear absorption coefficient, third-order nonlinear optical susceptibility, and semiconducting results for ZnO/Polystyrene composites films.

2. Materials and Methods

Fe₂O₃ doped ZnO powder was prepared by auto combustion method through mixing zinc nitrate, iron nitrate, and urea as an oxidizing agent with a certain calculated ratio. The mixed powders were placed in porcelain crucible to be burned in the furnace at about 370°C until the mixture homogenates, self-sustaining and rather fast combustion with enormous swelling producing white foamy and voluminous Fe₂O₃ doped ZnO. Then, furnace's temperature was increased up to 500°C, and the mixture was heated at this temperature for two hours before the furnace is switched off. Polystyrene (PS) was used as received without further purification with (MW= 35000 softening point (ASTM 28) 123-128 °C, density 1.06 g/mL at 25 °C from Sigma-Aldrich, Germany). The appropriate weight (5gm) of PS was dissolved in 100 ml of chloroform. The mixture was magnetically stirred continuously at room temperature for 2 hours until the mixture solution has a homogenous viscous appearance. The solution was left for 3 days before the addition of metal oxides filler to it. Different weights of the prepared powder with (5, 7.5, 10, and 12.5 wt. %) were added to the chloroform and magnetically stirred vigorously to ensure a high dispersion of the added nanoparticles for 1 hour and then ultrasonication for another 1 hour to prevent the agglomeration of the nanoparticles. The mixture was then mixed with the PS solution and stirred again for 1 hour, then ultra-sonication for 1 h. The polymers PS's final product reinforced with Fe₂O₃ doped ZnO nanoparticles was cast in glass Petri dishes and left 1 day for drying. The optical measurements of the prepared films were investigated using UV-Vis spectrophotometer type JASCO 570.

3. Results and Discussion

3.1. Dielectric, optical conductivity, and linear optical susceptibility results.

The films based on polystyrene (PS) filled with different concentrations of ZnO doped with Fe₂O₃ had a polycrystalline structure [37]. The oscillator energy E₀ and is the dispersion energy E_d were expressed as [40]:

\[ n^2(E) - 1 = \frac{E_0^2}{E_0^2 - E^2} \]
E is the photon energy. The dependence of \((n^2 - 1)^{-1}\) on \((\text{photon energy})^2\) \((hv)^2\) is shown in figure 1(a). The behavior of \((n^2 - 1)^{-1}\) is the same for all studied samples. The values for both \(E_0\) and \(E_d\) decreased with increasing the filler concentration. This is due to decreasing the \(E_{\text{gdir}}\) for these samples with filler [37], which allows electrons to absorb energy with lower values, and the vibration of these electrons decreases. Figure 1(b) shows the relation between \(n^2\) and \(\lambda^2\), \(N/m^*\) values were determined using [41]:

\[
\frac{eN}{4\pi c^2 \varepsilon_o m^*} \lambda^2
\]

The value of \(N/m^*\) increases with filler concentrations because of the increased free electrons with filler. The \(M_1\) and \(M_3\) derived from the relations [41]:

\[
E_{o}^2 = \frac{M_{-1}}{M_{-3}}
\]

\[
E_{d}^2 = \frac{M_{-1}}{M_{-3}}
\]

Table 1 shows the values of \(M_{1}\) and \(M_{3}\) for these thin films.

<table>
<thead>
<tr>
<th>Sample</th>
<th>(n_o)</th>
<th>(E_0) (eV)</th>
<th>(E_d) (eV)</th>
<th>(M_{+1}) (eV)</th>
<th>(M_{+3}) (eV)</th>
<th>(f) (eV)^2</th>
<th>(n_o)</th>
<th>(N/m^*)</th>
</tr>
</thead>
<tbody>
<tr>
<td>PS</td>
<td>0.20</td>
<td>6.10</td>
<td>8.30</td>
<td>6.91</td>
<td>2.85</td>
<td>47.79</td>
<td>1.55</td>
<td>9.1E+50</td>
</tr>
<tr>
<td>S1</td>
<td>0.28</td>
<td>5.90</td>
<td>8.10</td>
<td>5.99</td>
<td>2.51</td>
<td>35.91</td>
<td>1.54</td>
<td>1.5E+51</td>
</tr>
<tr>
<td>S2</td>
<td>2.10</td>
<td>5.70</td>
<td>6.30</td>
<td>5.35</td>
<td>2.28</td>
<td>28.60</td>
<td>1.45</td>
<td>3.1E+51</td>
</tr>
<tr>
<td>S3</td>
<td>2.25</td>
<td>5.50</td>
<td>5.20</td>
<td>4.59</td>
<td>2.21</td>
<td>21.07</td>
<td>1.39</td>
<td>4.9E+51</td>
</tr>
<tr>
<td>S4</td>
<td>2.30</td>
<td>4.30</td>
<td>4.90</td>
<td>4.59</td>
<td>2.21</td>
<td>21.07</td>
<td>1.46</td>
<td>6.2E+51</td>
</tr>
</tbody>
</table>

The oscillator strength \(f\) was calculated as following [42]:

\[
f = E_{o} \cdot E_{d}
\]

The values of \(f\) decrease with filler, as a result of decreasing both of \(E_0\) and \(E_d\). Another important parameter depending on \(E_0\) and \(E_d\) is that static refractive index \(n_o\), which was determined as [43]:
The dielectric loss $\varepsilon^\prime$ and dielectric tangent loss $\varepsilon^\prime\prime$ for these films were calculated as follows \[44\]:

$$
\varepsilon^\prime = (n^2 + k^2)
$$

$$
\varepsilon^\prime\prime = [(n^2 + k^2)^2 - (n^2 - k^2)^2]^{0.5}
$$

The effect of $h\nu$ on both of $\varepsilon^\prime$ and $\varepsilon^\prime\prime$ is shown in Figures 2(a,b), from this figures both of $\varepsilon^\prime$ and $\varepsilon^\prime\prime$ had the same behavior with $h\nu$ for all these samples, while $\varepsilon^\prime$ and $\varepsilon^\prime\prime$ increase with filler concentration, due to increasing the packing density\[37\].

![Figure 2. Dependence of (a) $\varepsilon^\prime$; (b) $\varepsilon^\prime\prime$ on $h\nu$ for ZnO films doped with Fe$_2$O$_3$.](image)

The optical conductivity was calculated from the following equations \[45\]:

$$
\sigma_1 = \left( \frac{\varepsilon^\prime\prime \cdot c}{2\lambda} \right)
$$

$$
\sigma_2 = \left( \frac{(1 - \varepsilon^\prime) \cdot c}{4\lambda} \right)
$$

Figures 3(a,b) show $\sigma_1$ and $\sigma_2$ dependence on $h\nu$ for these films, $\sigma_1$ and $\sigma_2$ increase with filler ratios and $h\nu$ for these samples, this due to increasing the electron mobility's with filler.

![Figure 3. Influence of $h\nu$ on (a) $\sigma_1$; (b) $\sigma_2$ for ZnO films doped with Fe$_2$O$_3$.](image)

Both of (VELF) and (SELF) for these samples were determined using \[41\]:

$$
\sigma = \frac{E_o}{E} + 1
$$

$$
\varepsilon^\prime = \left( n^2 + k^2 \right)
$$

$$
\varepsilon^\prime\prime = \left( [n^2 + k^2]^2 - [n^2 - k^2]^2 \right)^{0.5}
$$

$$
\sigma_1 = \left( \frac{\varepsilon^\prime\prime \cdot c}{2\lambda} \right)
$$

$$
\sigma_2 = \left( \frac{(1 - \varepsilon^\prime) \cdot c}{4\lambda} \right)
$$

$$
\lambda
$$

$$
\varepsilon
$$
The relation between VELF/SELF for these thin films is shown in Figure 4(a). Linear optical susceptibility $\chi^{(1)}$ describes the response of the material to an optical wavelength, $\chi^{(1)}$ was determined as [46]:

$$\chi^{(1)} = \frac{(n^2 - 1)}{4\pi}$$

The relation between $\chi^{(1)}$ and $h\nu$ for these films is shown in Figure 4(b). $\chi^{(1)}$ increased with increasing filler ratio. This means that there is a possibility for changing optical properties with slight doping for these samples.

3.2. Nonlinear optical properties.

The nonlinear refractive index $n_2$ was determined as [48–49]:

$$n_2 = \left(\frac{12\pi\chi^{(3)}}{n_o}\right)$$

The dependence of $n_2$ on $\lambda$ is in figure 5(a). $n_2$ increase with filler due to an increase in the packing density [37]. An important parameter is the third-order nonlinear optical susceptibility $\chi^{(3)}$, which was determined as [50]:

$$\chi^{(3)} = A \left[\frac{E_o \cdot E_d}{4\pi(E_o^2 - (h\nu)^2)}\right]^4$$

where, $A = 1.7 \times 10^{-10}$ e.s.u [50]. $\chi^{(3)}$ dependence on and $h\nu$ is shown in figure 5(b). $\chi^{(3)}$ increases with $h\nu$ and also with filler concentrations. On the other hand, nonlinear absorption coefficient $\beta_c$ was determined as follows [51]:

$$\beta_c = \frac{48 \cdot \pi^3 \chi^{(3)}}{n^2 c \cdot \lambda}$$
Figure 5(c) shows the influence of $h\nu$ on $\beta_c$. $\beta_c$ increases with filler because of high values of filler concentrations, the access number of electrons, and a large number of excited electrons.

Figure 6(a) shows the relation between $n_2$ and $\lambda$; (b) dependence of $(\chi^{(3)})$ on $h\nu$; (c) The influence of $h\nu$ on $\beta_c$ for ZnO films doped with Fe$_2$O$_3$.

3.3. Electrical results.

Electrical susceptibility $\chi^{(e)}$ means that the materials' ability for changing its electrical properties under the action of the electric field, and was determined as [52]:

$$\chi^{(e)} = \left( \frac{n^2 - k^2 - \varepsilon_r}{4\pi} \right)$$

Figure 6(a) shows the relation between $\chi^{(e)}$ and $h\nu$. $\chi^{(e)}$ increases with filler this is due to increasing the electron mobility. The relative permittivity $\varepsilon_r$ was calculated using the following relation [53]

$$\varepsilon_r = (\chi^{(e)} + 1)$$

The relation between $\varepsilon_r$ and $h\nu$ for these films is shown in Figure 6(b). It is clear that the values of $\varepsilon_r$ increase with filler concentrations. This could be attributed to the electron mobility increases with filler.
4. Conclusions

$E_d$ and $E_o$ values for ZnO/Polystyrene composite films decreased with Fe$_2$O$_3$ dopants ($E_d$ from 8.30 to 4.90 eV), and also $E_o$ had the values from (6.10 to 4.30 eV). The values of $N/m^*$ increased with filler, which increases free carrier. The values of $M_1$ and $M_3$ decrease with filler and also $n_o$ decrease slightly with filler ratios. $\varepsilon^1$ and $\varepsilon^3$ increase with filler ratios due to increasing packing factor of these samples with filler. Both $\sigma_1$ and $\sigma_2$ increase with filler as a result of increasing electron mobility. Moreover, $\chi(1)$ and the values of $n_2$ increase with filler ratios as a result of increasing the packing density of the investigated samples. The filler ratios affected $\chi(3)$ values which increased with filler due to the increase of excited electrons. This means that these samples highly responded to change their optical properties with filler. The nonlinear absorption coefficient $\beta_c$ increased with $h\nu$ for these samples. Also, both $\chi(e)$ and $\varepsilon$ increase with increasing filler. This means that the samples’ ability to change their electrical properties with electric field increases with filler concentrations increment. Finally, it is clear that the filler ratios play a very important role in enhancing most of the samples’ transparent properties, especially nonlinear optical properties. Therefore, these samples could be considered a promising material for nonlinear optical applications such as optical signal processing, optical computers, ultrafast switches, ultra-short pulsed lasers, sensors, laser amplifiers.

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Conflicts of Interest

The authors declare no conflict of interest.

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